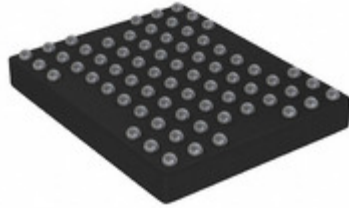


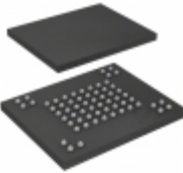




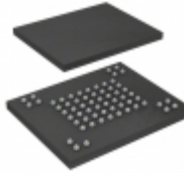
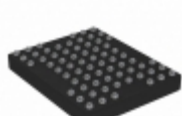
	<h2 style="color: #E67E22;">TC58NVG1S3HBAI6</h2>	
	Hersteller-Teilenummer:	TC58NVG1S3HBAI6
	Hersteller / Marke:	Toshiba Memory America, Inc.
	Teil der Beschreibung:	IC FLASH 2G PARALLEL 67VFBGA
Datenblätter:	 TC58NVG1S3HBAI6.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 653 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen	
Teilenummer	TC58NVG1S3HBAI6
Hersteller	Toshiba Memory America, Inc.
Beschreibung	IC FLASH 2G PARALLEL 67VFBGA
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	653 pcs Stock
detaillierte Beschreibung	FLASH - NAND (SLC) Memory IC 2Gb (256M x 8)
Serie	-
Technologie	FLASH - NAND (SLC)
Betriebstemperatur	-40°C ~ 85°C (TA)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	67-VFBGA
Supplier Device-Gehäuse	67-VFBGA (6.5x8)
Spannungsversorgung	2.7 V ~ 3.6 V
Speichertyp	Non-Volatile
Speichergröße	2Gb (256M x 8)
Zugriffszeit	25ns
Speicherformat	FLASH
Schreibzyklus Zeit - Wort, Seite	25ns
Speicherschnittstelle	Parallel
Verpackung	Tray
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	3 (168 Hours)
Andere Namen	TC58NVG1S3HBAI6JD0

TC58NVG1S3HBAI6 ist neu im Original, Suche TC58NVG1S3HBAI6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie TC58NVG1S3HBAI6 Toshiba Memory America, Inc. mit Garantie und Vertrauen. Anfrage TC58NVG1S3HBAI6: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>TC58NVG1S3HTA00 Toshiba Semiconductor and Storage IC EEPROM 2GBIT 25NS 48TSOP</p>	 <p>TC58NVG1S3HBAI4 Toshiba Memory America, Inc. IC FLASH 2G PARALLEL 63TFBGA</p>	 <p>TC58NVG1S3HTAI0 Toshiba Memory America, Inc. IC FLASH 2G PARALLEL 48TSOP I</p>	 <p>TC58NVG1S3ETA10B3H TOSHIBA TC58NVG1S3ETA10B3H TOSHIBA</p>
 <p>TC58NVG1S3HTA00 Toshiba Memory America, Inc. IC FLASH 2G PARALLEL 48TSOP I</p>	 <p>TC58NVG1S3HTA000 TSOP48 TSOP48 12+</p>	 <p>TC58NVG1S3HBAI4 Toshiba Semiconductor and Storage IC EEPROM 2GBIT 25NS 63FBGA</p>	 <p>TC58NVG1S3HBAI6 Toshiba Semiconductor and Storage IC EEPROM 2GBIT 25NS 67VFBGA</p>

heiße Teile

Mehr

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|-----------------|--------------------|------------------|-----------------|--------------------|
| TC58NC344AF | TC58NC5HJ8GSB-01 | TC58NC6623G6F | TC58NVG0S3AFT05 | TC58NVG0S3EBAI4 |
| TC58NVG0S3EBAI7 | TC58NVG0S3EBAI7LRH | TC58NVG0S3ETA00 | TC58NVG0S3ETA10 | TC58NVG0S3ETA10 |
| TC58NVG0S3HBAI6 | TC58NVG0S3HBAI6 | TC58NVG0S3HTAI0 | TC58NVG0S3HTAI0 | TC58NVG0S3HTAI0B4H |
| TC58NVG1S3EBAI4 | TC58NVG1S3EBAI5 | TC58NVG1S3ETA00 | TC58NVG1S3ETA00 | TC58NVG1S3ETA10 |
| TC58NVG1S3ETA10 | TC58NVG1S3ETA10 | TC58NVG1S3HBAI4 | TC58NVG1S3HBAI4 | TC58NVG1S3HBAI6 |
| TC58NVG1S3HTA00 | TC58NVG1S3HTA00 | TC58NVG2S0HTAI0 | TC58NVG2S0HTAI0 | TC58NVG2S3ETA00 |
| TC58NVG2S5HBAI6 | TC58NVG3S0FTA00B4H | TC58NVG4D2ETA100 | TC58NYG1S8HBAI6 | TC58NYG2S3ETA10 |
| TC58NYG2S3ETA10 | TC58NYM9S3EBAI4 | TC58RYG0S8EBAIA | TC58RYG0S8EBAIB | TC58RYG1S8EBAIA |
| TC58TEG5DCJTA00 | TC58V16BFT | TC58V64BFT | TC593002ECBTR | TC59LM806CTG-50 |
| TC59LM814CTG-50 | TC59LM818DKBI37 | TC59S1616AFT-10 | TC59S6416BFTL10 | TC59S6416CFT-80 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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